

PMV90ENE 30 V, N-channel Trench MOSFET

20 April 2016

Product data sheet

1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Logic level compatible
- Very fast switching
- Trench MOSFET technology
- ElectroStatic Discharge (ESD) protection > 2 kV HBM

3. Applications

- Relay driver
- High-speed line driver
- Low-side loadswitch
- Switching circuits

4. Quick reference data

Table 1. Quick reference data								
Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	30	V	
V _{GS}	gate-source voltage			-20	-	20	V	
I _D	drain current	V _{GS} = 10 V; T _{amb} = 25 °C; t ≤ 5 s	[1]	-	-	3.7	А	
Static characteristics								
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 3 A; T _j = 25 °C		-	54	72	mΩ	

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².



5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	3	D
2	S	source		
3	D	drain	1 2 TO-236AB (SOT23)	G G S S 017aaa255

6. Ordering information

Table 3. Ordering information						
Type number Package						
	Name	Description	Version			
PMV90ENE	TO-236AB	plastic surface-mounted package; 3 leads	SOT23			

7. Marking

Table 4. Marking codes	
Type number	Marking code
	[1]
PMV90ENE	%GH

[1] % = placeholder for manufacturing site code

8. Limiting values

Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Мах	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	30	V
V _{GS}	gate-source voltage			-20	20	V
I _D	drain current	V_{GS} = 10 V; T_{amb} = 25 °C; t ≤ 5 s	[1]	-	3.7	А
		V _{GS} = 10 V; T _{amb} = 25 °C	[1]	-	3	А
		V _{GS} = 10 V; T _{amb} = 100 °C	[1]	-	1.9	А
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	12	А
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	460	mW

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Symbol	Parameter	Conditions		Min	Мах	Unit
			[1]	-	1.1	W
		T _{sp} = 25 °C		-	4.5	W
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-dra	in diode	, ,				
I _S	source current	T _{amb} = 25 °C	[1]	-	1	А

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².

[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

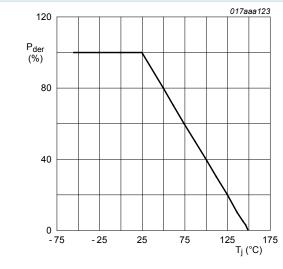
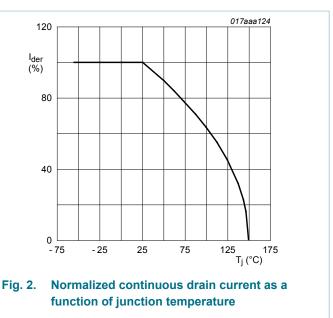


Fig. 1. Normalized total power dissipation as a function of junction temperature

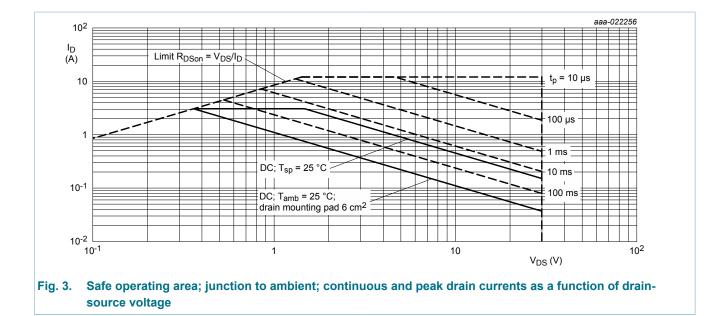
$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$



$$I_{der} = \frac{I_D}{I_D(25^{\circ}C)} \times 100 \%$$

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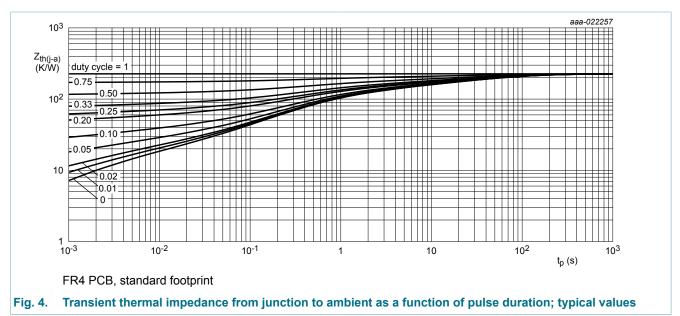


9. Thermal characteristics

Table 6. Thermal characteristics								
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit	
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	227	270	K/W	
			[2]	-	99	115	K/W	
		t ≤ 5 s	[2]	-	66	78	K/W	
R _{th(j-sp)}	thermal resistance from junction to solder point			-	20	28	K/W	

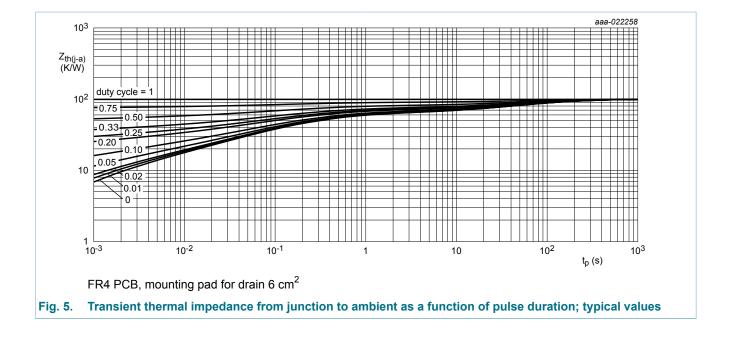
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm².



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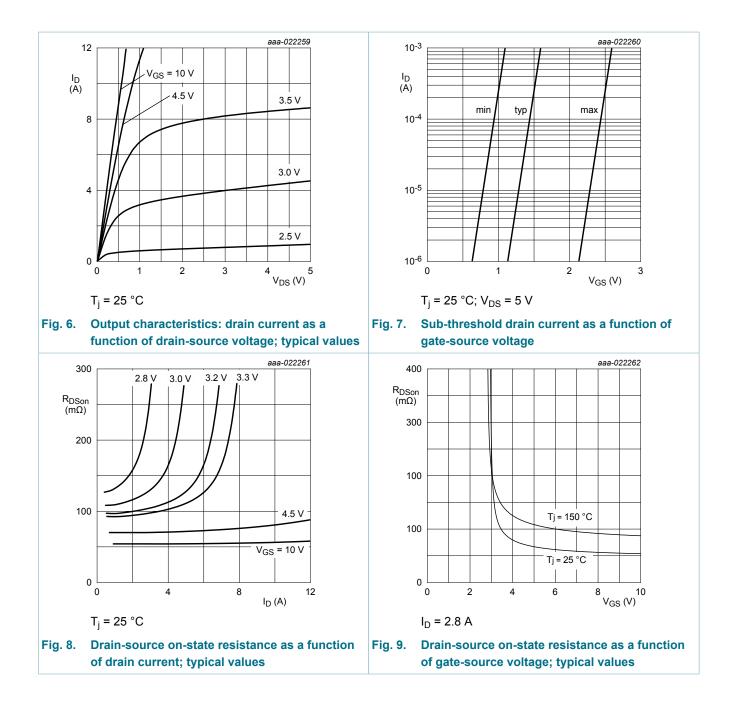


10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	octeristics	1				
V _{(BR)DSS}	drain-source breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	30	-	-	V
V _{GSth}	gate-source threshold voltage	I _D = 250 μA; V _{DS} =V _{GS} ; T _j = 25 °C	1	1.5	2.5	V
I _{DSS}	drain leakage current	V_{DS} = 30 V; V_{GS} = 0 V; T_j = 25 °C	-	-	1	μA
I _{GSS} gate lea	gate leakage current	V_{GS} = 20 V; V_{DS} = 0 V; T_j = 25 °C	-	-	10	μA
		V _{GS} = -20 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-10	μA
		V_{GS} = 10 V; V_{DS} = 0 V; T_j = 25 °C	-	-	2	μA
		V _{GS} = -10 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-2	μA
R _{DSon} drain-s	drain-source on-state	V _{GS} = 10 V; I _D = 3 A; T _j = 25 °C	-	54	72	mΩ
	resistance	V _{GS} = 10 V; I _D = 3 A; T _j = 150 °C	-	88	118	mΩ
		V _{GS} = 4.5 V; I _D = 2.6 A; T _j = 25 °C	-	70	100	mΩ
9 _{fs}	forward transconductance	V _{DS} = 10 V; I _D = 3 A; T _j = 25 °C	-	9	-	S
R _G	gate resistance	f = 1 MHz	-	11.5	-	Ω
Dynamic ch	aracteristics	· · · · · ·				
Q _{G(tot)}	total gate charge	V _{DS} = 15 V; I _D = 3 A; V _{GS} = 10 V;	-	3.6	5.5	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	0.4	-	nC
Q _{GD}	gate-drain charge	-	-	0.7	-	nC
C _{iss}	input capacitance	V _{DS} = 15 V; f = 1 MHz; V _{GS} = 0 V;	-	160	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	33	-	pF
C _{rss}	reverse transfer capacitance		-	26	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 15 V; I _D = 3 A; V _{GS} = 10 V;	-	6	-	ns
t _r	rise time	R _{G(ext)} = 6 Ω; T _j = 25 °C	-	6	-	ns
t _{d(off)}	turn-off delay time		-	11	-	ns
t _f	fall time		-	4	-	ns
Source-drai	n diode	1	I	1	1	
V _{SD}	source-drain voltage	I _S = 1 A; V _{GS} = 0 V; T _i = 25 °C	-	0.8	1.2	V

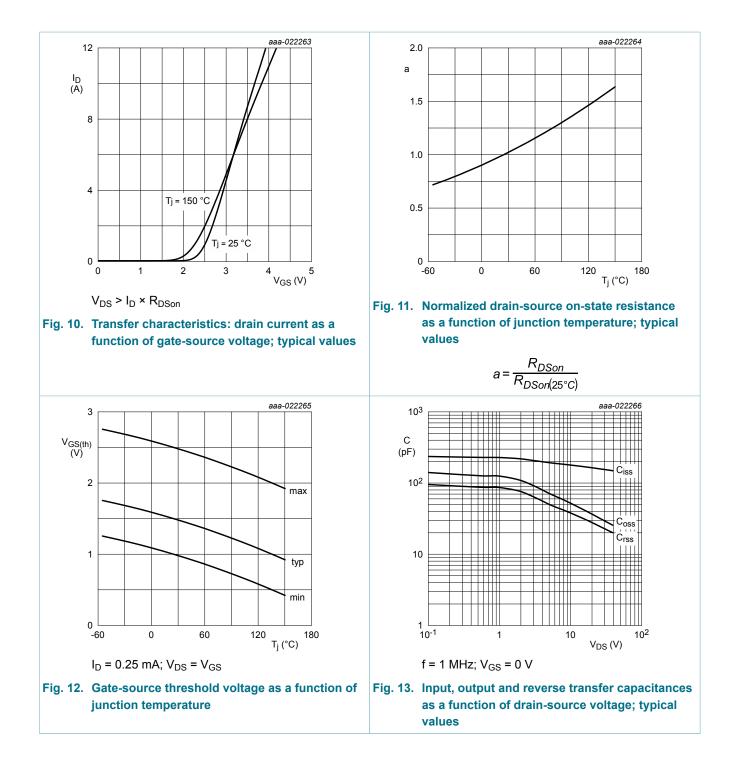
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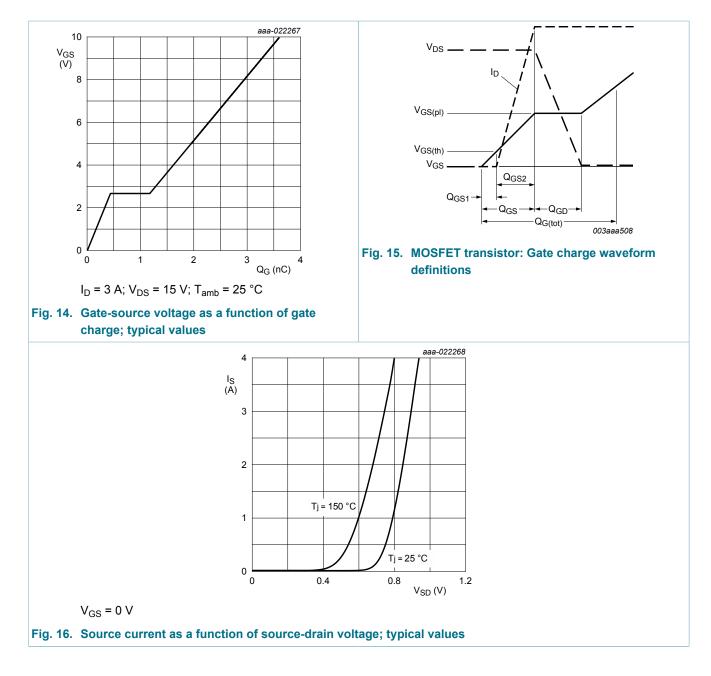
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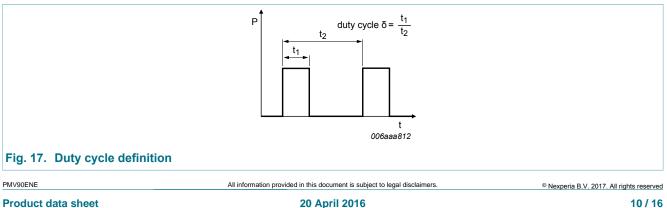


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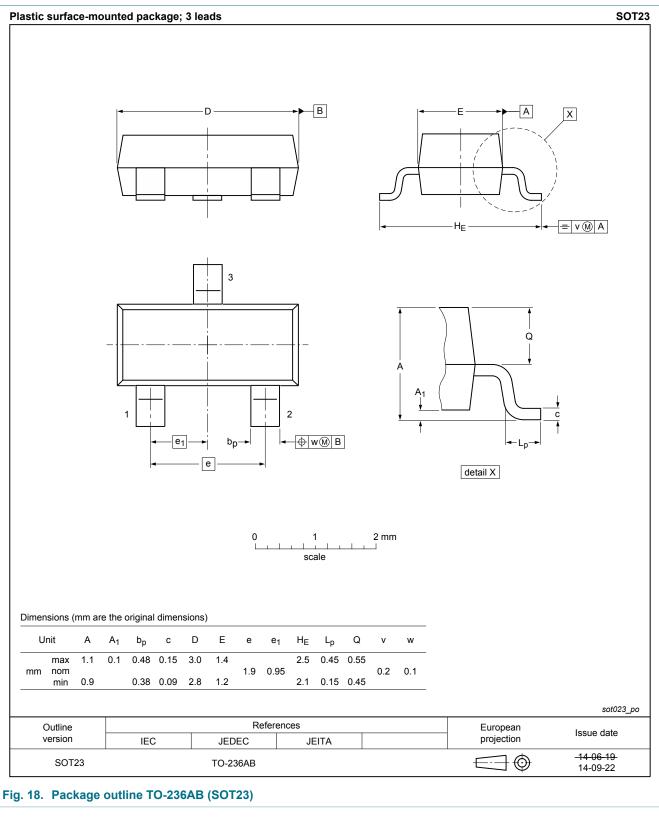
11. Test information



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12. Package outline

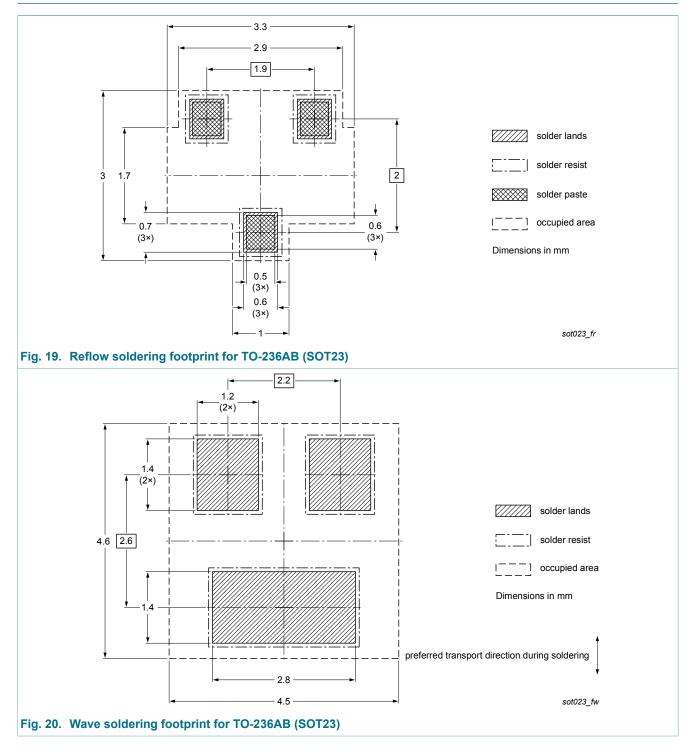


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13. Soldering



14. Revision history

Table 8. Revision history						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PMV90ENE v.1	20160420	Product data sheet	-	-		

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15. Legal information

15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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